

3/19 (TUE)	
<b>Nanomaterials 4</b> Chair: Junpei Sakurai (Nagoya University) Room C	<b>Plasma Science &amp; Technologies 1 Multiphase Plasma</b> Chair: Yasunori Tanaka (Kanazawa University) Room E
<b>9:30-10:00</b> <19aC01> <b>Invited Lecture</b> Tsuyoshi Moriya Tokyo Electron Technology Solutions Limited "Data Analytics Approach for Optimizing Plasma Process and Equipment Condition"	<b>9:30-10:00</b> <19aE01> <b>Invited Lecture</b> Young-Hoon Song Korea Institute of Machinery and Materials "Plasma Technologies for Reducing Emissions from Diesel Engine"
<b>10:00-10:15 1041</b> <19aC02O> Akihiro Tanaka "Continuous Si rod Growth from Powder Feedstocks Via Plasma Flash Evaporation" <sup>1</sup> Akihiro Tanaka, <sup>1</sup> Ryoshi Ohta, <sup>2</sup> Masashi Dougakiuchi and <sup>1</sup> Makoto Kambara <sup>1</sup> The University of Tokyo <sup>2</sup> Shimane Institute for Industrial Technology	<b>10:00-10:15 1170</b> <19aE02O> Yang Liu "Aqueous Reactions in Non-equilibrium Atmospheric Pressure Plasma-activated Ringer's Lactate Solutions" <sup>1</sup> Yang Liu, <sup>1</sup> Kenji Ishikawa, <sup>1</sup> Hiromasa Tanaka, <sup>1</sup> Hiroshi Hashizume, <sup>1</sup> Takyoshi Tsutsumi, <sup>1</sup> Fumitaka Kikkawa, <sup>1</sup> Kae Nakamura, <sup>2</sup> Masaaki Mizuno, <sup>1</sup> Shinya Toyokuni and <sup>1</sup> Hiroki Kondo <sup>1</sup> Nagoya University <sup>2</sup> Nagoya University Hospital
<b>10:15-10:30 1186</b> <19aC03O> Ranjit R. Borude "Synthesis, Characterization, and Study of Electrical Properties of Tin oxide-Graphene Composite Synthesized by Liquid Phase Plasma" Ranjit Borude, Hirotugu Sugiura, Kenji Ishikawa, Takayoshi Tsutsumi, Hiroki Kondo and Masaru Hori Nagoya University	<b>10:15-10:30 1122</b> <19aE03O> Yoshinobu Inagaki "Reaction Frequencies of CTTS Transition-induced Solvated Electrons in Ionic Liquids Interacting with Low-Pressure Argon Plasmas" Yoshinobu Inagaki and Koichi Sasaki Hokkaido University
<b>10:30-10:45 1266</b> <19aC04O> Liwen Su "Two-dimensional Simulations of Multi-hollow Geometry VHF SiH <sub>4</sub> /H <sub>2</sub> Plasma using Plasma Hybrid Code" Li-Wen Su, Weiting Chen, Kiichiro Uchino and Yoshinobu Kawai Kyushu University	<b>10:30-10:45 1163</b> <19aE04O> Jun-Seok Oh "International Study of Plasma Activated Water: Chemical Composition of RONS" <sup>1</sup> Jun-Seok Oh, <sup>2</sup> Endre Szili, <sup>3</sup> Robert Short, <sup>4</sup> Akimitsu Hatta, <sup>5</sup> Mineo Hiramatsu and <sup>5</sup> Masafumi Ito <sup>1</sup> Osaka City University <sup>2</sup> University of South Australia <sup>3</sup> Lancaster University <sup>4</sup> Kochi University of Technology <sup>5</sup> Meijo University

<b>10:45-11:00 1322</b> <19aC05O> Hiroki Kondo "Effects of Hydroxy Group on Synthesis Rate and Crystallinity of Nanographene by In-liquid Plasma" <sup>1</sup> Hiroki Kondo, <sup>2</sup> Keigo Takeda, <sup>1</sup> Kenji Ishikawa, <sup>1</sup> Takayoshi Tsutsumi, <sup>1</sup> Makoto Sekine and <sup>1</sup> Masaru Hori <sup>1</sup> Nagoya University <sup>2</sup> Meijo University	<b>10:45-11:00 1279</b> <19aE05O> Hyun-Ha Kim "Plasma Calndle: A New Type of Atmospheric Pressure Plasma Jet" Hyun-Ha Kim Kim, Yoshiyuki Teramoto, Nozomi Takeuchi and Atsushi Ogata National Institute of Advanced Industrial Science and Technology (AIST)
<b>Nanomaterials 5</b>  Chair: Osamu Nakatsuka (Nagoya University) Room C	<b>Plasma Science &amp; Technologies 2</b> <b>Plasma Sources</b> Chair: Young-Hoon Song (Korea Institute of Machinery and Materials) Room E
<b>11:15-11:45</b> <19aC06I> <b>Invited Lecture</b> Masao Sakuraba Tohoku University "Epitaxy and In-Situ Doping in Low-Energy Plasma CVD Processing for Group-IV Semiconductor Nanoelectronics"	<b>11:15-11:45</b> <19aE06I> <b>Invited Lecture</b> Keigo Takeda Meijo University "Systematic Diagnostics of AC Excited Atmospheric Pressure Plasma Jet for Bio-medical Applications"
<b>11:45-12:00 1012</b> <19aC07O> Weijian Ma "Preparation of CeO <sub>2</sub> Nanoparticles by Pulsed Plasma in Liquid Method" Weijian Ma, Tsutomu Mashimo, Shota Tamura, Makoto Tokuda, Shinichi Yoda, Masayuki Tsushima, Michio Koinuma, Akihisa Kubota, Hiroshi Isobe and Akira Yoshiasa Kumamoto University	<b>11:45-12:00 1162</b> <19aE07O> Manh Hung Chu "Optimized Waveguide Structure for Atmospheric Pressure Microwave Plasma" Manh Hung Chu, Haruka Suzuki and Hirotaka Toyoda Nagoya University
<b>12:00-12:15 1013</b> <19aC08O> Shota Tamura "Synthesis of Pd-Fe Series Alloy Nanoparticles by Pulsed Plasma in Liquid" Shota Tamura, Tsutomu Mashimo, Kenta Yamamoto, Zhazgul Kelgenbaeva, Weijian Ma, Xuesong Kang, Masayuki Tsushima, Michio Koinuma, Hiroshi Isobe and Akira Yoshiasa Kumamoto University	<b>12:00-12:15 1147</b> <19aE08O> John Raymund Brusas "Plasma-induced Desorption of VOCs from Surfactant-modified Natural Zeolites" John Raymund Brusas, Mark Jeffry De Leon, Eleanor Olegario and Magdaleno Vasquez Jr. University of the Philippines-Diliman
<b>12:15-12:30 1251</b> <19aC09O> Worawan Bhanthumnavin "Surface Modification of Cellulose Membranes from Water Hyacinth with Sulfur Hexafluoride plasma for Biomedical Applications" Boonchoat Paosawatyanyong, Yannawit Chanpirom and Worawan Bhanthumnavin Chulalongkorn University	<b>12:15-12:30 1290</b> <19aE09O> Takayoshi Tsutsumi "Ligh Source Wavelength Characteristics for Silicon-Wafer Temperature Measurement by Frequency-Domain Low-coherence Interferometry" <sup>1</sup> Takayoshi Tsutsumi, <sup>1</sup> Kenji Ishikawa, <sup>2</sup> Takayuki Ohta, <sup>2</sup> Masafumi Ito, <sup>1</sup> Hiroki Kondo, <sup>1</sup> Makoto Sekine and <sup>1</sup> Masaru Hori <sup>1</sup> Nagoya University <sup>2</sup> Meijo University

Lunch Break 12:30-14:00

**Topical session 1****Current Status and Future Perspective of GaN / Si Technology**

Chair: Tetsuya Suemitsu (Tohoku University), Makoto Miyoshi (Nagoya Institute of Technology)  
RoomB

**14:00-14:30 Invited Lecture**

&lt;19pB10I&gt;

Yang Liu

San Yat-sen University

"High-mobility E-mode Recessed Gate GaN MISFETs with High-quality MIS Interface Fabricated by Selective Area Growth"

**14:30-15:00 Invited Lecture**

&lt;19pB11I&gt;

Qian Sun

Suzhou Institute of Nano-Tech and Nano-Bionics (SINANO), Chinese Academy of Sciences (CAS)

"GaN-on-Si Optoelectronics and Power Electronics"

**15:00-15:30 Invited Lecture**

&lt;19pB12I&gt;

Debaleen Biswas

Nagoya Institute of Technology

"Improvement in Breakdown Voltage of Fully-vertical GaN p-n Diode on Si"

**15:30-16:00 Invited Lecture**

&lt;19pB13I&gt;

Atsushi Nishikawa

ALLOS Semiconductors GmbH

"High Crystal Quality GaN-on-Si to Achieve Excellent Isolation and Dynamic Performance without Carbon Doping"

**Bio Applications 4**

Chair: Endre Szili (University of South Australia)  
Room D

**16:15-16:45**

&lt;19pD14I&gt;

**Invited Lecture**

Hyunjoo J Lee

KAIST

"Biomedical Microsystems for Neural Interface"

**Plasma Science & Technologies 3****Etching**

Chair: Keigo Takeda (Meijo University)  
Room E

**16:15-16:45**

&lt;19pE14I&gt;

**Invited Lecture**

Atsushi Komuro

Tohoku University

"Numerical Simulation for Chemical Reactions in Atmospheric-Pressure Streamer Discharge in Air"

**Nitride Semiconductors 4****Vertical GaN Electronic Devices**

Chair: Atsushi Nishikawa (ALLOS Semiconductors GmbH)  
Room F

**16:15-16:45**

&lt;19pF14I&gt;

**Invited Lecture**

Tetsuo Narita

Toyota Central R&amp;D Labs., Inc.

"Overview of Carrier Compensation in n-type and p-type GaN Layers Grown by Metalorganic Vapor Phase Epitaxy"

**16:45-17:15**

&lt;19pD15I&gt;

**Invited Lecture**

Yoko Yamanishi

Kyushu University

"Emerging Functions of Plasma-induced Bubbles"

**16:45-17:00 1320**

&lt;19pE15O&gt;

Yusuke Fukunaga

"Organic High Aspect Ratio Pattern Formation with Self-Limitation Manner by Plasma-Controlled Process based on Substrate Temperature Measurement"

Yusuke Fukunaga, Takayoshi Tsutsumi, Kenji Ishikawa, Hiroki Kondo, Makoto Sekine and Masaru Hori Nagoya University

**16:45-17:00**

&lt;19pF15O&gt;

"MCTS Studies of Hole Traps in n-GaN Induced by He Ion Implantation"

<sup>1</sup>Yutaka Tokuda, <sup>1</sup>Ken Iyoda,<sup>2</sup>Joji Ito, <sup>2</sup>Takahide Yagi and<sup>3</sup>Kenji Shiojima<sup>1</sup>Aichi Institute of Technology, Japan<sup>2</sup>SHI-ATEX Co., Ltd., Japan<sup>3</sup>University of Fukui, Japan**17:00-17:15 1174**

&lt;19pE16O&gt;

Minoru Sasaki

"Over 100μm Length Single Spiral Silicon Micro-Trench with 3-Step Smooth Sidewalls to Deposit Superconducting Material for Magnetic Energy Storage"

<sup>1</sup>Minoru Sasaki, <sup>2</sup>Yasuhiro Suzuki,<sup>2</sup>Kazuhiko Adachi, <sup>2</sup>Tatsumi Hioki and<sup>2</sup>Tomoyoshi Motohiro<sup>1</sup>Toyota Technological Institute<sup>2</sup>Nagoya University

<b>17:15-17:30 1029 &lt;19pD16O&gt;</b> Mohamed Mathar Sahib Ibrahim Khaleelullah "Bioimaging and Photothermal Study of NaGdF4:Yb:Tm@Cu Core-Shell Nanostructures" <sup>1</sup> Mohamed Mathar Sahib Ibrahim Khaleelullah, <sup>1</sup> Kyohei Sugimoto, <sup>1</sup> Asahi Tanaka, <sup>2</sup> Thangaraju Dheivasingamani, <sup>1</sup> Wataru Inami, <sup>1</sup> Yoshimasa Kawata, <sup>1</sup> Yosuke Shimura and <sup>1</sup> Yasuhiro Hayakawa <sup>1</sup> Shizuoka University <sup>2</sup> PSG Institute of Technology and Applied Research	<b>17:15-17:30 1313 &lt;19pE17O&gt;</b> Takahiro Omichi "GaN film Etching at H-added Chlorine Plasma at High Temperature at 400°C" Takahiro Omichi, Atsushi Tanide, Kenji Ishikawa, Takayoshi Tsutsumi, Hiroki Kondo, Makoto Sekine and Masaru Hori Nagoya University	<b>17:15-17:30 1058 &lt;19pF16O&gt;</b> Takashi Ishida "Study of Trench Gate Structure on GaN Vertical Trench MOSFET" <sup>1,2</sup> Takashi Ishida, <sup>1,3</sup> Shinji Yamada, <sup>4</sup> Tetsuo Narita and <sup>1</sup> Tetsu Kachi <sup>1</sup> Nagoya University <sup>2</sup> Toyota Motor Corporation <sup>3</sup> ULVAC, Inc. <sup>4</sup> Toyota Central R&D Labs., Inc.
<b>17:30-17:45 1248 &lt;19pD17O&gt;</b> TaiChun Tsai "Preparation of Thin Films Containing Carboxylic and Amine Functionalities on Rigid Gas Permeable Contact Lens by PECVD" TaiChun Tsai and MengJiy Wang National Taiwan University of Science and Technology	<b>17:30-17:45 1250 &lt;19pE18O&gt;</b> Xu Li "A study of In-situ X-ray Photoelectron Spectroscopy Surface Analysis in Development of Atomic Layer Etch for GaN/AlGaN based Power Device Fabrication" Xu Li, Dilini Hemakumara, Yen-Chun Fu, David Moran and Iain Thayne University of Glasgow	<b>17:30-17:45 1133 &lt;19pF17O&gt;</b> Shinji Yamada "Slope-down-bias Etching Techniques for Suppression of Plasma-induced Damage of GaN in ICP-RIE" <sup>1,2</sup> Shinji Yamada, <sup>1,2</sup> Hideki Sakurai, <sup>1</sup> Masato Omori, <sup>2</sup> Toshiyuki Nakamura, <sup>2</sup> Ryuichiro Kamimura, <sup>1</sup> Jun Suda and <sup>1</sup> Tetsu Kachi <sup>1</sup> Nagoya University <sup>2</sup> ULVAC, Inc.
<b>17:45-18:00 1256 &lt;19pD18O&gt;</b> Pietro Favia "Plasma Deposition of Antibacterial Nanocapsules on De-cellularized Biologic Scaffolds for Tissue Engineering" <sup>1</sup> Annalisa Treglia, <sup>2</sup> Fabio Palumbo, <sup>2</sup> Roberto Gristina, <sup>2</sup> Eloisa Sardella, <sup>3</sup> Martina Ramella, <sup>4</sup> Luca Fusaro, <sup>3</sup> Francesca Boccafoschi and <sup>5,2</sup> Pietro Favia <sup>1</sup> University of Bari Aldo Moro <sup>2</sup> Institute of Nanotechnology, CNR <sup>3</sup> University of Piemonte Orientale A. Avogadro <sup>4</sup> TissueGraft s.r.l, Novara Biotechnologies and <sup>5</sup> Biopharmaceutics, University of Bari	<b>11:15-11:30 1246 &lt;19aE19O&gt;</b> Hossain Md Amzad Bangladesh "Characteristics of Aluminum Doped Zinc Oxide (AZO) Film Prepared using RF Magnetized Plasma Sputtering Source with Square-shaped Magnet Setup" <sup>1</sup> Md Amzad Hossain, M. A. M. Patwary, Y. Nakamura and K. Sugawara <sup>1</sup> Jessore University of Science and Technology <sup>2</sup> Saga University <sup>3</sup> Comilla University	

Banquet 18:15-20:15